



Parameter	Rating	Units
AC Operating Voltage	20 - 240	V_{rms}
Load Current	2	A_{rms}
On-State Voltage Drop	1.15	V_{rms} (at $I_L = 2A_{rms}$)
Blocking Voltage	600	V_P

Features

- Load Current up to $2A_{rms}$
- $600V_P$ Blocking Voltage
- 5mA Sensitivity
- Zero-Crossing Detection
- DC Control, AC Output
- Optically Isolated
- TTL and CMOS Compatible
- Low EMI and RFI Generation
- High Noise Immunity
- Machine Insertable, Wave Solderable

Applications

- Programmable Control
- Process Control
- Power Control Panels
- Remote Switching
- Gas Pump Electronics
- Contactors
- Large Relays
- Solenoids
- Motors
- Heaters

Description

CPC1976 is an AC Solid State Switch utilizing dual power SCR thyristor outputs. This device also includes zero-cross turn-on circuitry and is specified with a blocking voltage of $600V_P$.

In addition, tightly controlled zero-cross circuitry ensures low noise switching of AC loads by minimizing the generation of transients. The optically coupled input and output circuits provide $3750V_{rms}$ of isolation and noise immunity between the control and load circuits. As a result, the CPC1976 is well suited for industrial environments where electromagnetic interference would disrupt the operation of plant facility communication and control systems.

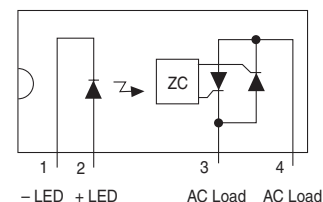
Approvals

- UL Recognized Component: File E69938
- CSA Certified Component: File 043639

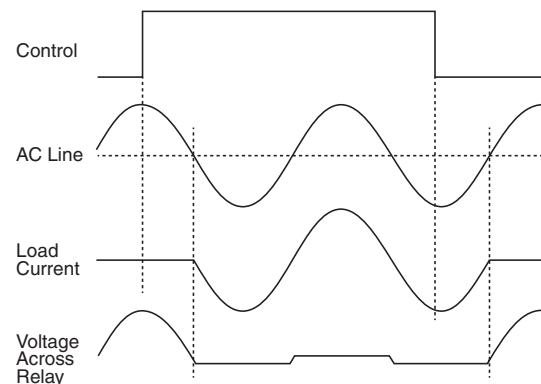
Ordering Information

Part #	Description
CPC1976Y	4-Pin (8-Pin Body) SIP (25/Tube)

Pin Configuration



Zero-Cross Waveforms



Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Blocking Voltage (V_{DRM})	600	V_P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation ¹	150	mW
Total Power Dissipation ²	2400	mW
Isolation Voltage, Input to Output	3750	V_{rms}
ESD, Human Body Model	4	kV
i^2t for Fusing (1/2 Sine Wave, 50Hz)	8	A ² s
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate linearly 1.33 mW / °C

² Derate linearly 20 mW / °C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics @ 25°C

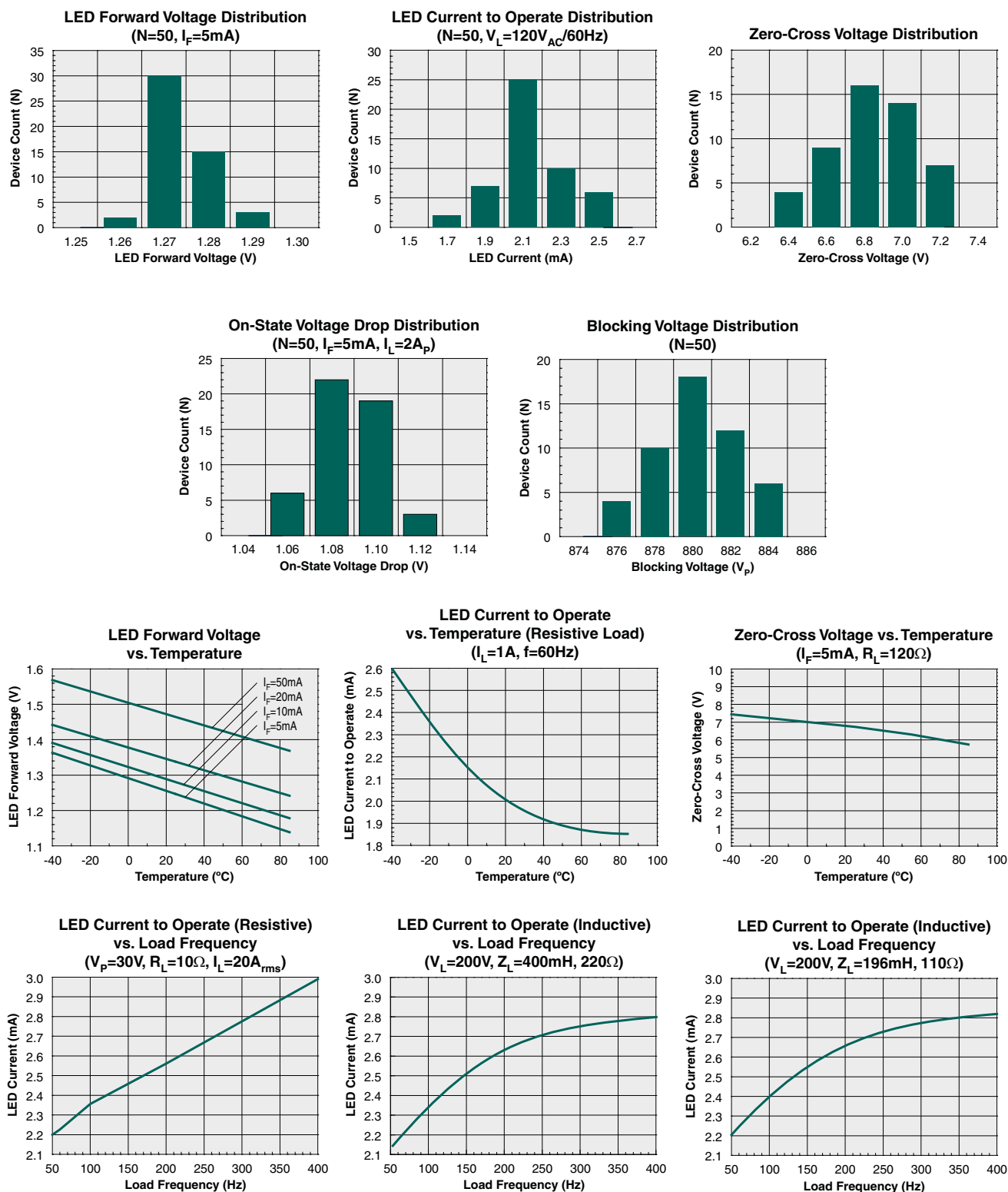
Parameters	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Load Current, Continuous	$V_L = 120-240V_{rms}$	I_L	0.070	-	2	A_{rms}
Maximum Surge Current	$t \leq 16ms$	I_{PK}	-	-	20	A
Off State Leakage Current	V_{DRM}	I_{LEAK}	-	-	10	μA
On-State Voltage Drop	$I_L = 2A_P$	-	-	1.1	1.25	V_P
Critical Rate of Rise	-	dv/dt	1000	1200	-	V/ μs
Switching Speeds	$I_F = 5 mA$					
Turn-on		t_{on}	-	-	0.5	cycles
Turn-off		t_{off}	-	-	0.5	cycles
Zero-Cross Turn-On Voltage ¹	1st half-cycle	-	-	7	20	V
	Subsequent half-cycle	-	-	-	5	V
Holding Current	-	I_H	-	-	75	mA
Latching Current	-	I_L	-	-	100	mA
Operating Frequency	-		20	-	500	Hz
Load Power Factor for Guaranteed Turn-On ²	60Hz	PF	0.25	-	-	-
Input Characteristics						
Input Control Current to Activate ³	60Hz	I_F	-	-	5	mA
Input Drop-out Voltage	-	-	0.8	-	-	V
Input Voltage Drop	$I_F = 5mA$	V_F	0.9	1.2	1.4	V
Reverse Input Current	$V_R = 5V$	I_R	-	-	10	μA
Common Characteristics						
Input to Output Capacitance	-	C_{IO}	-	-	3	pF

¹ Zero Cross 1st half-cycle @ <100Hz.

² Snubber circuits may be required at low power factors.

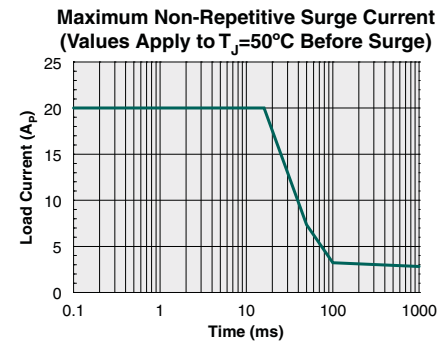
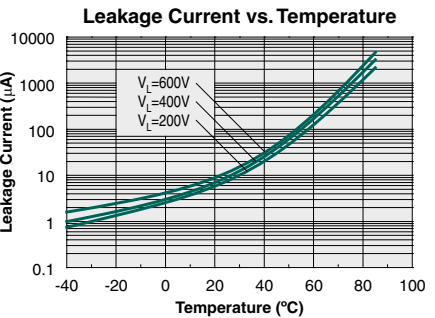
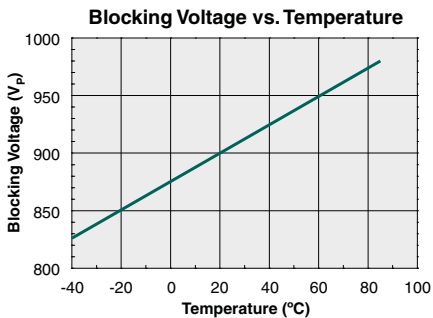
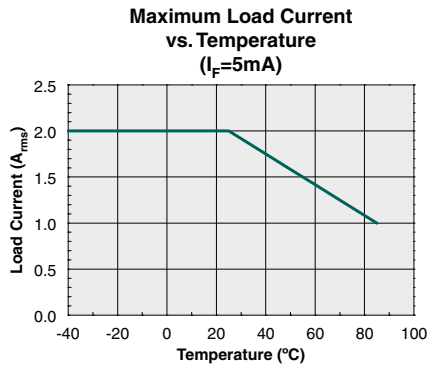
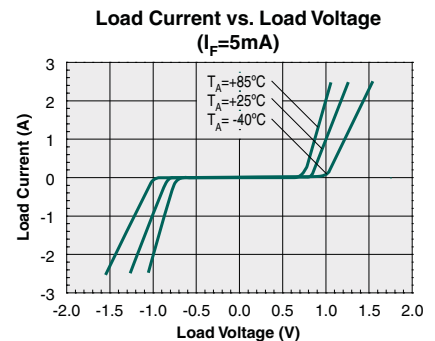
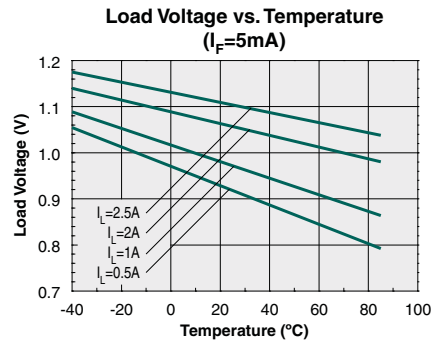
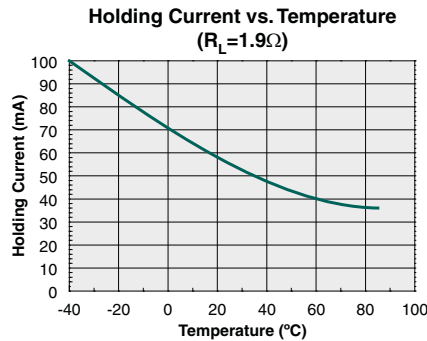
³ For high-noise environments, or for high-frequency operation, use $I_F \geq 10mA$.

PERFORMANCE DATA @ 25°C (Unless Otherwise Noted)*



* The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

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Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
CPC1976Y	MSL 1

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
CPC1976Y	245°C for 30 seconds

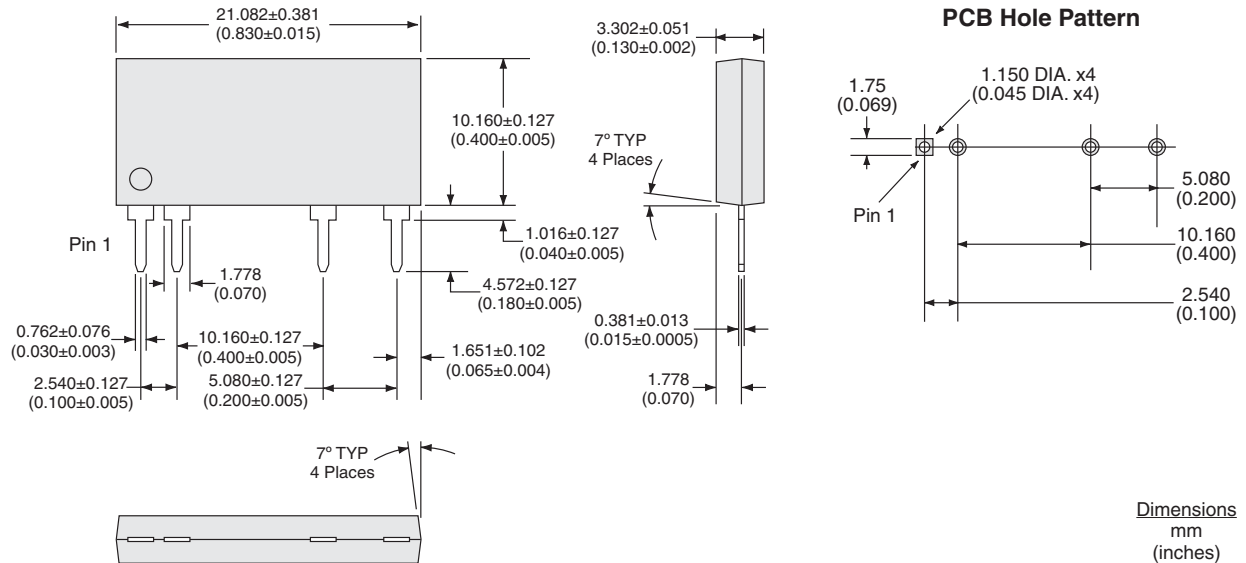
Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since IXYS Integrated Circuits Division employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake could be necessary if a wash is used after solder reflow processes. Chlorine- or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.



MECHANICAL DIMENSIONS

CPC1976Y



For additional information please visit our website at: www.ixysic.com

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